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VDAC electronics: 1. VDAC-hexo(gluco)kinase generator of the mitochondrial outer membrane potential 2

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ABSTRACT

The simplest mechanism of the generation of the mitochondrial outer membrane potential (OMP) by the VDAC 22 (voltage-dependent anion channel)-hexokinase complex (VHC), suggested earlier, and by the VDAC-glucokinase 23 complex (VGC), was computationally analyzed. Even at less than 4% of VDACs bound to hexokinase, the calculat- 24 ed OMP is high enough to trigger the electrical closure of VDACs beyond the complexes at threshold concentra- 25 tions of glucose. These results confirmed our previous hypothesis that the Warburg effect is caused by the 26 electrical closure of VDACs, leading to global restriction of the outer membrane permeability coupled to aerobic 27 glycolysis. The model showed that the inhibition of the conductance and/or an increase in the voltage sensitivity 28 of a relatively small fraction of VDACs by factors like tubulin potentiate the electrical closure of the remaining free 29 VDACs. The extrusion of calcium ions from the mitochondrial intermembrane space by the generated OMP, pos- 30 itive inside, might increase cancer cell resistance to death. Within the VGC model, the known effect of induction 31 of ATP release from mitochondria by accumulated glucose-6-phosphate in pancreatic beta cells might result not 32 only of the known effect of GK dissociation from the VDAC-GK complex, but also of a decrease in the free energy 33 of glucokinase reaction, leading to the OMP decrease and VDAC opening. We suggest that the VDAC-mediated 34 electrical control of the mitochondrial outer membrane permeability, dependent on metabolic conditions, is a 35 fundamental physiological mechanism of global regulation of mitochondrial functions and of cell death. 36

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1. Introduction 42

VDAC, the most abundant protein of the mitochondrial outer mem-43 brane (MOM¹) [1–4], is universally accepted as responsible for the con-44 trol of metabolite fluxes between mitochondria and the cytosol [3-7]. 45 46 This porin has been demonstrated to directly relate to many physiological processes and pathologies [5,7–9]. VDAC has even been considered 47 as a governator of global mitochondrial functions both in health and dis-48ease [5]. However, experimental results related to the VDAC-mediated 49 50regulation of the MOM permeability and of cell death are confusing and contradictory, and the mechanisms responsible for this regulation 51remain poorly understood [4,10-12]. 52

53Although VDAC's electrical properties have been studied in detail [1–4,10,13], it has been generally considered as a permanently open 54

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pore under physiological conditions. Meanwhile, a large body of literature 55 has been accumulated showing that VDAC conductance in living cells 56 should be regulated [4,5,8-10,12-15]. It has been widely assumed 57 that the MOM permeability is controlled by a partial or complete block- 58 age of VDAC by various cytosolic proteins like tubulin [13-19], or in 59 general, by various anti- and pro-apoptotic factors [5,7,8,10,12]. Many 60 cases of apparently anomalous behavior of mitochondria and of global 61 suppression of mitochondrial functions have been attributed to such 62 reversible blockage-type regulation of the MOM permeability [5]. 63

On the other hand, it is unlikely, according to Mannella et al. [20], 64 that VDAC simply converts the MOM in a coarse sieve. We could add 65 in this respect, that it is unlikely that the permeability of this sieve is 66 simply regulated by only "molecular corks", as by hexokinase (HK) 67 bound to VDAC, for example [21]. Meanwhile, the role of VDAC's highly 68 conserved voltage gating properties remains to be the main unresolved 69 question [4]. This question seems to be fundamental and can be an- 70 swered possibly by finding the missing players of the MOM permeabil- 71 ity regulation. 72

Earlier, we have proposed several steady-state mechanisms of the 73 generation of metabolically-dependent OMP to demonstrate that the 74 electrical closure-opening of VDAC might represent a physiological 75 mechanism of regulation of the MOM permeability [22-24]. Experimen-76 tal evidence of the generation of the negative OMP in living cells has 77 been obtained by Porcelli et al. [25], although it is not yet clear, to 78

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Abbreviations: VDAC, voltage-dependent anion channel; HK, hexokinase: GK, glucokinase; VHC, VDAC-HK complex; VGC, VDAC-GK complex; MIMS, mitochondrial intermembrane space; MOM, mitochondrial outer membrane; OMP, outer membrane potential; IMP, inner membrane potential; ANT, adenine nucleotide translocator; N_H, the percentage of VDACs bound to HK or to GK; N_{VS} , the percentages of voltage sensitive VDACs; N_{NS} , the percentage of voltage non-sensitive VDACs, TE, tubulin-like effectors; N_{TE}, the percentage of VDACs bound to TE; NI, the percentage of VDACs completely blocked by an inhibitor

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what extent the metabolically-dependent inner membrane surface
potential influenced the reported data, as it has been analyzed earlier
[26].

82 According to one of the possible mechanisms of OMP generation, suggested earlier, the inner membrane potential (IMP) might be partly 83 applied to the MOM through the intermembrane contact sites com-84 posed of adenine nucleotide translocator (ANT) and VDAC [23,24]. The 85 86 same idea has recently been expressed by Pedersen [9]. In cancer cells, 87 in addition, the resistance of the ANT-VDAC-HK contact sites has been 88 suggested to decrease due to the free energy of the HK reaction applied to the contact sites, thus increasing the OMP [23,24]. The possible expla-89 nation of the Warburg effect has been proposed on the basis of global 90 electrical closure of VDACs beyond the contact sites, due to the generat-91ed OMP. A similar concept has been developed in the last years by other 92authors [5,27], although without pointing to the electrical character of 93 the MOM permeability suppression in cancer cells. 94

The simplest of the proposed mechanisms of the OMP generation 95 96 has been based on the VDAC-HK complex only [23,24], because, for example, the mitochondrial intermembrane contact sites have not 97 been found in the subpopulation HT29 Glc⁺ of adenocarcinoma cells, 98 although HK was predominantly bound to mitochondria [28]. Computa-99 tional analysis of this model could represent certain interest for under-100 101 standing possible mechanisms of the regulation of aerobic glycolysis and cell death. It has been discovered that in cancer cells, a large propor-102 tion of HK is associated with mitochondria [29,30 and reference therein] 103 that has also been found to increase cancer cell resistance to death 104 [8,9,11,12,31,32]. In addition, cancer cells have been characterized by a 105106 high rate of aerobic glycolysis and by a mitochondrial HK activity up to more than two orders of magnitude higher than in normal cells 107 [33,34]. It has been found that both the HK binding to VDAC and the 108 glucose phosphorylation reaction contribute to the protective effects 109 110 of HK-I and HK-II against cell death [35]. It might be related to a de-111 crease of the calcium concentration in the MIMS due to the positive OMP generation by VHC, according to the physical principles described 112earlier [23,24]. 113

In the present work, we developed the VHC and VGC models of 114 generation of the OMP, with the Gibbs free energy of kinase reactions 115as a driving force, as a battery in an equivalent electrical circuit. The 116 calculations showed that the OMP value directly depends on the per-117 centage of VDACs bound to HK, on the glucose concentration, and on 118 the presence of tubulin-like effectors (TE). The calculated OMPs were 119 120 high enough to electrically close VDAC. The positive sign of the OMP generated by the VHC might explain a high resistance of cancer cells 121 to death as a result of calcium extrusion from the mitochondrial inter-122 123 membrane space (MIMS). The model can be applied to pancreatic beta cells, for mitochondria of which high values of the OMP were calculated 124 125using the VGC model. Development and computational analysis of such and similar models seems to be an important approach to the further 126understanding of cell energy metabolism regulation, as well as of many 127cases of apparently anomalous behavior of mitochondria reviewed and 128analyzed in detail in [5]. 129

130 2. Materials and methods

131 2.1. The VDAC-hexokinase complex model

According to the VHC model shown in Fig. 1A, ATP from the MIMS 132and glucose from the cytoplasm are used by HK bound to VDAC in the 133 MOM, liberating ADP back into the MIMS and producing cytoplasmic 134glucose-6-phosphate. 100% of all VDACs in the MOM can be expre-135ssed as the sum of the percentage of VDACs bound to HK (N_H), of 136the percentages of the voltage sensitive VDACs (N_{VS}), and of voltage 137 non-sensitive VDACs (N_{NS}), as well as of the percentage of VDACs 138 bound to tubulin-like effectors (TE) influencing VDAC voltage sensi-139140 tivity and/or partially blocking it (N_{TE}), and even of the percentage of



Fig. 1. The main principle of the OMP generation by the VDAC-hexokinase complex. A -VHC functioning leads to a charge separation across the MOM. The generated potential leads to the free VDAC closure strongly restricting ADP release from the MIMS to recover ATP in the cytoplasm. It represents the suggested anti-turbo mechanism of regulation of aerobic glycolysis allowing usage of mitochondrial ATP for the first stage of glycolysis in cancer cells (dotted lines). Ions H⁺, Cl⁻, K⁺, Mg²⁺, Ca²⁺ permeate through free VDACs in the MOM, achieving their electrochemical equilibrium. MPU - mitochondrial potassium uniporter; MCU - mitochondrial calcium uniporter. B - An equivalent electrical circuit of the VHC model: the battery E_H represents Gibbs free energy of the hexokinase reaction. The battery internal resistance, R_H, depends on the percentage of VDACs bound to HK. The resistance of the fraction of free voltage non-sensitive VDACs (as low sensitive VDAC3, for example) is presented as the resistance R_{NS} connected in parallel to the resistance R_{VS} of the remaining voltage gating VDACs. According to Ohm's law, the OMP generation results from voltage division on the equivalent resistance of free VDACs (R_{NS} and R_{VS}), that might be influenced by various VDAC effectors, and on the internal resistance of the battery R_H. Note, as the VDACs begin to close, their increasing resistance leads to further OMP increase by the mechanism of positive feedback control, allowing the MOM permeability regulation that depends on the glucose concentration and on the [ATP]₄ [ADP]_s ratio.

VDACs completely blocked by some inhibitors (N₁):

$$100 = N_{H} + N_{VS} + N_{NS} + N_{TE} + N_{I}$$
(1)

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The conductance g_{NS} (resistance $R_{NS} = 1/g_{NS}$ in Fig. 1B) of the N_{NS} 144 fraction is not affected by the OMP, thus we can write $g_{NS} = N_{NS}$, 145 expressing conductance in arbitrary units, a.u. The maximum conductance of the MOM was taken as 100 a.u., for 100% of all VDACs in the 147 open state.

The conductance g_{VS} (resistance R_{VS} in Fig. 1B) of the fraction N_{VS} 149 can be expressed as the function of the OMP ($\Delta \psi_o$) using an equation 150 similar to that published earlier [22–24], at an arbitrary voltage-sensitivity 151 parameter "*S1*": 152

$$\mathbf{g}_{\mathrm{VS}} = \mathbf{N}_{\mathrm{VS}} \cdot \mathbf{P}_{c1} + \mathbf{N}_{\mathrm{VS}} \cdot (1 - \mathbf{P}_{c1}) \cdot \exp\left(-\left(S1 \cdot \Delta \psi_o s\right)^2\right). \tag{2}$$

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We used here $S1 = 40 \text{ V}^{-1}$ allowing almost complete VDAC closure 155 at $\Delta \psi_o = \pm 40 \text{ mV}$, as shown in Fig. 2a and b. The parameter P_{c1} is the 156 VDAC relative conductance in the closed state, which was set in the 157 range of 0.25–0.50 for various calculations [15,36–38]. 158

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